No	lto		Specifications		Toot Mot	thod			
No.	Ite		Temperature Compensating Type	Test Method					
1	Operating Temperature Range		−55 to +125°C	Reference temperat (2Δ, 3Δ, 4Δ: 20°C)	ure: 25°C				
2	2 Rated Voltage		See the previous pages.		The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, VP-P or VO-P, whichever is larger, should be maintained within the rated voltage range.				
3	Appearar	ice	No defects or abnormalities	Visual inspection					
4	Dimensio	ns	Within the specified dimensions	Using calipers (GRM02 size is based on Microscope)					
5	Dielectric Strength		No defects or abnormalities	No failure should be observed when 300%* of the rate is applied between the terminations for 1 to 5 seconds provided the charge/discharge current is less than 50n			5 seconds,		
6	Insulation Resistance		C≦0.047μF: More than 10,000MΩ C>0.047μF: More than 500Ω · F C: Nominal Capacitance	The insulation resistance should be measure voltage not exceeding the rated voltage at 2 max. and within 2 minutes of charging, providischarge current is less than 50mA.		0/25°C and 75%RH			
7	Capacita	nce	Within the specified tolerance	The capacitance/Q/D.F. should be measured a			at 20/25°C at the		
8	Q		30pF and over: Q≥1000 30pF and below: Q≥400+20C C: Nominal Capacitance (pF)	Capacitance Item Frequency Voltage	ı	pelow mo	0re than 1000pF 1±0.1kHz 1±0.2Vrms		
		No bias	. ",	The capacitance cha					
9	Capacitance Temperature Characteristics Drift		Within the specified tolerance (Table A-1) Within ±0.2% or ±0.05pF (Whichever is larger.) *Do not apply to 1X/25V	each specified temp. stage. The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5 (5C: +25 to +125°C/ΔC: +20 to +125°C: other temp. coeffs.: +25 to +85°C/+20 to +85°C) the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as Table A-1. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the step 1, 3 and 5 by the cap. value in step 3. Step Temperature (°C) 1 Reference Temperature ±2 2 -55±3 (for ΔC to 7U/1X) -25±3 (for ther TC) 3 Reference Temperature ±2 4 125±3 (for ΔC) 85±3 (for OC) 85±3 (for OC) 85±3 (for OC)					
10	Adhesive Strength of Termination		No removal of the terminations or other defect should occur. C	Solder the capacitor to the test jig (glass epox Fig. 1a using an eutectic solder. Then apply 10 parallel with the test jig for 10±1 sec. The soldering should be done either with an in reflow method and should be conducted with a soldering is uniform and free of defects such a *1N (GRM02), 2N (GRM03), 5N (GRM15, GR Type a b GRM02 0.2 0.56 GRM03 0.3 0.9 GRM15 0.4 1.5 GRM18 1.0 3.0 GRM15 0.4 1.5 GRM18 1.0 3.0 GRM21 1.2 4.0 GRM31 2.2 5.0 GRM31 2.2 5.0 GRM31 2.2 5.0 GRM32 2.2 5.0 GRM33 3.5 7.0 GRM43 3.5 7.0 GRM55 4.5 8.0		10N* force in iron or using the h care so that the h as heat shock.			

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No.	ltem		Specifications Temperature Compensating Type	Test Method				
11	Appearance Capacitance Vibration Resistance Q		No defects or abnormalities	Solder the capacit	Solder the capacitor on the test jig (glass epoxy board) in			
			Within the specified tolerance	same manner and				
			30pF and over: Q≧1000 30pF and below: Q≥400+20C C: Nominal Capacitance (pF)	The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).				
		Appearance	No marking defects	Solder the capacit	or on the test ji	g (glass epoxy	y board) shown	
	Capacitance Change		Within ±5% or ±0.5pF (Whichever is larger)	in Fig. 2a using an eutectic solder. Then apply a force in the direction shown in Fig. 3a for 5±1 sec. The soldering should be done by the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.				
12			20 50 Pressurizing speed : 1.0mm/sec. Pressurize R230 Flexure : ≦1 Capacitance meter 45 Fig. 3a	Fig. 2a t: 1.6mm (GRM02/03/15: t: 0.8mm) Type a b c GRM02 0.2 0.56 0.23 GRM03 0.3 0.9 0.3 GRM15 0.4 1.5 0.5 GRM18 1.0 3.0 1.2 GRM21 1.2 4.0 1.65 GRM21 1.2 4.0 1.65 GRM31 2.2 5.0 2.0 GRM32 2.2 5.0 2.0 GRM32 3.5 7.0 3.7 GRM43 3.5 7.0 3.7 GRM55 4.5 8.0 5.6				
13	3 Solderability of Termination		75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-810 rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in an eutectic solder solution f 2±0.5 seconds at 230±5°C or Sn-3.0Ag-0.5Cu solder sol for 2±0.5 seconds at 245±5°C.			solution for	
			The measured and observed characteristics should satisfy the specifications in the following table.					
		Appearance	No defects or abnormalities	Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the capacitor in an eutectic solder or Sn-3.0Ag-0.5Cu solder solution at 270±5°C for 10±0.5 seconds. Set at room temperature for 24±2 hours, then measure.				
	Resistance to	ldering 30pF and over: Q≥1000	·				Sn-3.0Ag-0.5Cu	
14	Soldering			•Preheating for GRM32/43/55				
	Heat	Q	30pF and below: Q≧400+20C	Step	Temperatur	е	Time	
			C: Nominal Capacitance (pF)	1	100 to 120°	С	1 min.	
		I.R.	More than $10,000M\Omega$ or $500\Omega \cdot F$ (Whichever is smaller)	_ 2	170 to 200°	U	1 min.	
		Dielectric Strength	No defects	_				

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lo.	o. Item		Specifications Temperature Compensating Type	Test Method						
			The measured and observed characteristics should satisfy the specifications in the following table.							
		Appearance	No defects or abnormalities	Fix the capacitor to the supporting jig in the same						
15		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	manner and under the same conditions as (10). Perform the five cycles according to the four heat tre shown in the following table. Set for 24±2 hours at room temperature, then measurements.						
	Temperature Cycle	Q	30pF and over: Q≧1000	Step	1	2	3	4		
			30pF and below: Q≧400+20C		Min.	Room	Max.	Room		
			C: Nominal Capacitance (pF)	Temp. (°C)	Operating Temp. +0/–3	Temp.	Operating Temp. +3/–0	Temp.		
		I.R.	More than $10,000M\Omega$ or $500\Omega \cdot F$ (Whichever is smaller)	Time (min.)	30±3	2 to 3	30±3	2 to 3		
		Dielectric Strength	No defects							
			The measured and observed characteristics should satisfy the specifications in the following table.							
		Appearance	No defects or abnormalities							
16	Humidity	Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	Set the capacitor at 40±2°C and in 90 to 95% humidity for						
	(Steady State)	Q	30pF and over: Q≥350 10pF and over 30pF and below: Q≥275+2.5C 10pF and below: Q≥200+10C	500±12 hours. Remove and set for 24±2 hours at room temperature, t measure.				, then		
			C: Nominal Capacitance (pF)	_						
		I.R.	More than 1,000M Ω or 50 Ω · F (Whichever is smaller)							
			The measured and observed characteristics should satisfy the specifications in the following table.							
		Appearance	No defects or abnormalities	Apply the rated voltage at 40±2°C and 90 to 95% humic 500±12 hours. Remove and set for 24±2 hours at room						
7	Humidity	Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)					•		
•	Load	Q	30pF and over: Q≥200 30pF and below: Q≥100+10C/3	temperature, then measure. The charge/discharge curre						
			C: Nominal Capacitance (pF)							
		I.R.	More than $500M\Omega$ or $25\Omega \cdot F$ (Whichever is smaller)							
			The measured and observed characteristics should satisfy the specifications in the following table.							
		Appearance	No defects or abnormalities	Apply 200% of the rated voltage at the maximum temperature ±3°C for 1000±12 hours. Set for 24±2 hours at room temperature, then me. The charge/discharge current is less than 50mA.						
	High _ Temperature Load	Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)			e maximum ope	mum operating			
18		Q	30pF and over: Q≥350 10pF and over 30pF and below: Q≥275+2.5C 10pF and below: Q≥200+10C			mperatu	hours. perature, then measure.			
				1						
			C: Nominal Capacitance (pF)							

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Table A-1

(1)

	Nominal Values (ppm/°C)*1	Capacitance Change from 25°C (%)						
Char.		- 55		-30		-10		
		Max.	Min.	Max.	Min.	Max.	Min.	
5C	0± 30	0.58	-0.24	0.40	-0.17	0.25	-0.11	
6C	0± 60	0.87	-0.48	0.59	-0.33	0.38	-0.21	
6P	-150± 60	2.33	0.72	1.61	0.50	1.02	0.32	
6R	-220± 60	3.02	1.28	2.08	0.88	1.32	0.56	
6S	-330± 60	4.09	2.16	2.81	1.49	1.79	0.95	
6T	-470± 60	5.46	3.28	3.75	2.26	2.39	1.44	
7U	-750±120	8.78	5.04	6.04	3.47	3.84	2.21	
1X	+350 to -1000	_	_	_	_	_	_	

^{*1:} Nominal values denote the temperature coefficient within a range of 25°C to 125°C (for Δ C)/85°C (for other TC).

(2)

		Capacitance Change from 20°C (%)						
Char.	Nominal Values (ppm/°C)*2	-55		-25		-10		
		Max.	Min.	Max.	Min.	Max.	Min.	
2C	0± 60	0.82	-0.45	0.49	-0.27	0.33	-0.18	
3C	0±120	1.37	-0.90	0.82	-0.54	0.55	-0.36	
4C	0±250	2.56	-1.88	1.54	-1.13	1.02	-0.75	
2P	-150± 60	_	_	1.32	0.41	0.88	0.27	
3P	-150±120	_	_	1.65	0.14	1.10	0.09	
4P	-150±250	_	_	2.36	-0.45	1.57	-0.30	
2R	-220± 60	_	_	1.70	0.72	1.13	0.48	
3R	-220±120	_	_	2.03	0.45	1.35	0.30	
4R	-220±250	_	_	2.74	-0.14	1.83	-0.09	
28	-330± 60	_	_	2.30	1.22	1.54	0.81	
38	-330±120	_	_	2.63	0.95	1.76	0.63	
48	-330±250	_	_	3.35	0.36	2.23	0.24	
2T	-470± 60	_	_	3.07	1.85	2.05	1.23	
3T	-470±120	_	_	3.40	1.58	2.27	1.05	
4T	-470±250	_	_	4.12	0.99	2.74	0.66	
3U	-750±120	_	_	4.94	2.84	3.29	1.89	
4U	-750±250	_	_	5.65	2.25	3.77	1.50	

^{*2:} Nominal values denote the temperature coefficient within a range of 20°C to 125°C (for Δ C)/85°C (for other TC).